

Description

The DIODES 74AUP1T34Q is an automotive, AEC-Q qualified, single-bit, dual-supply, non-inverting buffer translator suitable for transmitting a single logic bit across different voltage domains. It is a uni-directional translator from A to Y. The input Pin A has input switching thresholds related to V_{CCA} , operating from 0.9 V to 3.6 V. The output Pin Y has a HIGH level output voltage that tracks V_{CCB} , also operating from 0.9V to 3.6V. This arrangement allows for universal low-voltage translation between any voltages from 0.9V to 3.6V.

The three-state feature occurs when the V_{CCA} power supply voltages are zero. This is also an I_{OFF} feature and allows the output to remain in a high-impedance state, preventing damaging backflow currents and providing power-down electrical isolation of up to 3.6V. If the V_{CCB} is at ground, the input circuits at Pin A are disabled and no input current flows regardless of any applied voltage between 0 and 3.6V.

The 74AUP1T34Q is available in the SOT353 package, and is specified for operation from -40°C to $+125^{\circ}\text{C}$ among all supply voltages. The wide temperature ranges and high ESD tolerance facilitate their use in harsh applications.

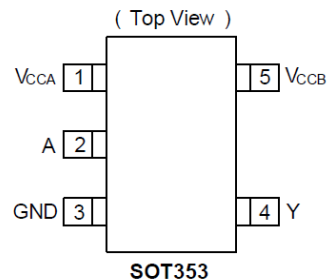
Features

- Temperature range: -40°C to $+125^{\circ}\text{C}$
- Wide supply voltage range:
 - $V_{CC(A)}$: from 0.9V to 3.6V
 - $V_{CC(B)}$: from 0.9V to 3.6V
- $\pm 6\text{mA}$ output drive at 3V
- Low-static power consumption; $I_{CC} = 5 \mu\text{A}$ (maximum)
- High noise immunity (100mV hysteresis typical)
- I_{OFF} supports partial-power-down mode operation
- I_{OFF} controlled by V_{CCB} being at 0V
- Input isolation when V_{CCA} is ground; no input current even when floating
- ESD protection exceeds JESD 22
 - Exceeds 5000V Human Body Model (A114)
 - Exceeds 1000V Charged Device Model (C101)
- Latch-up exceeds 100mA per JESD 78, class II
- **Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)**
- **Halogen and Antimony Free. "Green" Device (Note 3)**
- **The DIODES 74AUP1T34Q is suitable for automotive applications requiring specific change control; this part is AEC-Q100 qualified, PPAP capable, and manufactured in IATF16949 certified facilities.**

<https://www.diodes.com/quality/product-definitions/>

- Notes:
1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.
 2. See <https://www.diodes.com/quality/lead-free/> for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
 3. Halogen- and Antimony-free "Green" products are defined as those which contain $<900\text{ppm}$ bromine, $<900\text{ppm}$ chlorine ($<1500\text{ppm}$ total Br + Cl) and $<1000\text{ppm}$ antimony compounds.

Pin Assignments



Applications

- Voltage level translation:
 - Well suited to join logic types operating at different voltages
- Power-down signal isolation:
 - When $V_{CCA} = \text{GND}$ output is three-state
 - When $V_{CCB} = \text{GND}$ input is disabled and may be left floating
- Wide array of products such as:
 - Vehicle electronic control units (ECU)
 - Vehicle autonomous systems
 - Advanced driver assistance systems (ADAS)
 - Industrial devices
 - Personal electronics
 - Telecommunications

Pin Descriptions

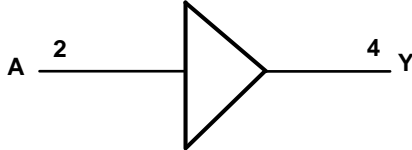
Pin Name	Pin SOT353	Function
V _{CCA}	1	Supply for pin A
A	2	Data Input (threshold based on V _{CCA})
GND	3	Ground
Y	4	Data Output (V _{OH} based on V _{CCB})
NC	-	NC (can be connected to any potential)
V _{CCB}	5	Supply for pin Y

Function Table

Supply Voltage		Input	Output
V _{CCA}	V _{CCB}	A	Y
0.9 V to 3.6 V	0.9 V to 3.6 V	L	L
0.9 V to 3.6 V	0.9 V to 3.6 V	H	H
0	0.9 V to 3.6 V	X	Z
0 V to 3.6 V	0	Isolated (Note 4)	Z

Note: 4. Floating input pin is allowed for this case

Logic Diagram



Absolute Maximum Ratings (Note 5) (@T_A = +25°C, unless otherwise specified.)

Symbol	Parameter	Rating	Unit
ESD HBM	Human Body Model ESD Protection	5	kV
ESD CDM	Charged Device Model ESD Protection	1	kV
V _{CCA} , V _{CCB}	Supply Voltage Range	-0.3 to +4.0	V
V _I	Input Voltage Range	-0.5 to +4.6	V
V _O	Voltage Applied to Output in High Impedance or I _{OFF} State	-0.5 to +4.6	V
V _O	Voltage Applied to Output in High or Low State	-0.5 to +4.6	V
I _{IK}	Input Clamp Current V _I <0	-50	mA
I _{OK}	Output Clamp Current	-50	mA
I _O	Continuous Output Current	±50	mA
	Continuous Current Through V _{CCA} or GND	±100	mA
T _J	Operating Junction Temperature	-40 to +150	°C
T _{STG}	Storage Temperature	-65 to +150	°C

Note: 5. Stresses beyond the absolute maximum may result in immediate failure or reduced reliability. These are stress values and device operation should be within recommend values.

Recommended Operating Condition (Note 6) (@ $T_A = +25^\circ\text{C}$, unless otherwise specified.)

Symbol	Parameter	V_{CCA}	V_{CCB}	Min	Max	Units
V_{CCA}	Operating Voltage	—	—	0.9	3.6	V
V_{CCB}	Operating Voltage	—	—	0.9	3.6	V
V_{IH}	High-Level Input Voltage	0.9V to 1.95V	0.9V to 3.6V	$0.65 \times V_{CCA}$	—	V
		2.3V to 2.7V	0.9V to 3.6V	1.6	—	
		3V to 3.6V	0.9V to 3.6V	2	—	
V_{IL}	Low-Level Input Voltage	0.9V	0.9V to 3.6V	—	$0.3 \times V_{CCA}$	V
		1V to 1.95V	0.9V to 3.6V	—	$0.35 \times V_{CCA}$	
		$0.35 \times V_{CCA}$	0.9V to 3.6V	—	0.7	
		3V to 3.6V	0.9V to 3.6V	—	0.8	
T_A	Operating Free-Air Temperature			-40	+85	$^\circ\text{C}$

Note: 6. Test condition for each of the three package types: Device mounted on JEDEC standard PCB per JESD51, with minimum recommended pad layout.

Electrical Characteristics (@ $T_A = +40^\circ\text{C}$ to $+85^\circ\text{C}$, unless otherwise specified.)

Symbol	Parameter	Test Conditions	V_{CCA}	V_{CCB}	$T_A = -40^\circ\text{C}$ to $+85^\circ\text{C}$		Unit
					Min	Max	
V_{OH}	High Level Output Voltage	$I_{OH} = -100\mu\text{A}$	0.9V to 3.6V	0.9V to 3.6V	$V_{CCB} - 0.2$	—	V
		$I_{OH} = -0.25\text{mA}$	0.9V to 1V	0.9V to 1V	$0.75 \times V_{CCB}$	—	
		$I_{OH} = -1.5\text{mA}$	1.2V	1.2V	1	—	
		$I_{OH} = -2\text{mA}$	1.65V	1.65V	1.32	—	
		$I_{OH} = -3\text{mA}$	2.3V	2.3V	1.9	—	
		$I_{OH} = -6\text{mA}$	3V	3V	2.72	—	
V_{OL}	Low-Level Output Voltage	$I_{OL} = 100\mu\text{A}$	0.9V to 3.6V	0.9V to 3.6V	—	0.1	V
		$I_{OL} = 0.25\text{mA}$	0.9V to 1V	0.9V to 1V	—	0.1	
		$I_{OL} = 1.5\text{mA}$	1.2V	1.2V	—	$0.3 \times V_{CCB}$	
		$I_{OL} = 2\text{mA}$	1.65V	1.65V	—	0.31	
		$I_{OL} = 3\text{mA}$	2.3V	2.3V	—	0.31	
		$I_{OL} = 6\text{mA}$	3V	3V	—	0.31	
I_I	Input Current	$V_I = V_{CCA}$ or GND	0.9V to 3.6V	0.9V to 3.6V	—	± 1	μA
I_{OFF}	Off State Current	A Pin	0V	0 to 3.6V	—	± 5	μA
		Y Pin	0 to 3.6V	0	—	± 5	
I_{CCA}	Supply Current	$V_I = V_{CCA}$ or GND $I_O = 0\text{mA}$	0.9V to 3.6V	0.9V to 3.6V	—	5	μA
			0.9V to 3.6V	V_{CCA}	—	2	
			0V	0V to 3.6V	—	1	
			0.9V to 3.6V	0V	—	1	
I_{CCB}	Supply Current	$V_I = V_{CCA}$ or GND $I_O = 0\text{mA}$	0.9V to 3.6V	0.9V to 3.6V	—	5	μA
			0.9V to 3.6V	V_{CCA}	—	2	
			0V	0V to 3.6V	—	1	
			0.9V to 3.6V	0V	—	1	
$I_{CCA} + I_{CCB}$	Supply Current	$V_I = V_{CCA}$ or GND $I_O = 0\text{mA}$	1.2 to 3.6V	1.2 to 3.6V	—	20	μA
C_I	Input Capacitance	A pin $V_I = 3.3\text{V}$ or GND	3.3V	3.3V	—	4	pF
C_O	Output Capacitance	Y pin $V_O = 3.3\text{V}$ or GND	0V	3.3V	—	7	pF

Package Characteristics

Symbol	Parameter	Package	Test Conditions	Min	Typ	Max	Unit
θ_{JA}	Thermal Resistance Junction-to-Ambient	SOT353	(Note 7)	—	318	—	$^\circ\text{C/W}$
θ_{JC}	Thermal Resistance Junction-to-Case	SOT353	(Note 7)	—	156	—	$^\circ\text{C/W}$

Note: 7. Test condition for each of the three package types: Device mounted on JEDEC standard PCB per JESD51, with minimum recommended pad layout.

Switching Characteristics

Parameter	Test Conditions	V _{CCA}	V _{CCB}	Min	Typ	Max	Units
t_{pLH}/t_{pHL} Propagation delay time low-to-high output / high- to-low output	C _L = 5pF	0.9V	0.9V	—	25	—	ns
			1.2V	—	18	—	
			1.65V	—	16.2	—	
			2.3V	—	16.3	—	
			3V	—	16.8	—	
	C _L = 5pF	1.2V	0.9V	—	—	42.5	
			1.2V	—	—	24.9	
			1.65V	—	—	23.2	
			2.3V	—	—	22.6	
			3V	—	—	22.5	
	C _L = 5pF	1.65V	0.9V	—	—	40	
			1.2V	—	—	10.7	
			1.65V	—	—	8.84	
			2.3V	—	—	8.08	
			3V	—	—	7.88	
	C _L = 5pF	2.3V	0.9V	—	—	41.3	
			1.2V	—	—	8.02	
			1.65V	—	—	5.73	
			2.3V	—	—	4.92	
			3V	—	—	4.2	
C _L = 5pF	3V	0.9V	—	—	42.5		
		1.2V	—	—	7.61		
		1.65V	—	—	5.5		
		2.3V	—	—	4.65		
		3.0V	—	—	4.39		
t_{pLH}/t_{pHL} Propagation delay time low-to-high output / high- to-low output	C _L = 10pF	0.9V	0.9V	—	28.9	—	ns
			1.2V	—	19.8	—	
			1.65V	—	17.9	—	
			2.3V	—	18	—	
			3V	—	18.5	—	
	C _L = 10pF	1.2V	0.9V	—	—	43.22	
			1.2V	—	—	12.33	
			1.65V	—	—	9.57	
			2.3V	—	—	8.81	
			3V	—	—	8.61	
	C _L = 10pF	1.65V	0.9V	—	—	40.44	
			1.2V	—	—	9.21	
			1.65V	—	—	6.57	
			2.3V	—	—	5.5	
			3V	—	—	4.73	
	C _L = 10pF	2.3V	0.9V	—	—	41.56	
			1.2V	—	—	8.3	
			1.65V	—	—	5.54	
			2.3V	—	—	4.42	
			3V	—	—	4.01	
C _L = 10pF	3V	0.9V	—	—	42.81		
		1.2V	—	—	7.87		
		1.65V	—	—	4.55		
		2.3V	—	—	3.8		
		3.0V	—	—	3.36		

Switching Characteristics

Parameter	Test Conditions	V _{CCA}	V _{CCB}	Min	Typ	Max	Units
t_{pLH}/t_{pHL} Propagation delay time low-to-high output / high- to-low output	C _L = 15pF	0.9V	0.9V	—	30.6	—	ns
			1.2V	—	21.6	—	
			1.65V	—	19.6	—	
			2.3V	—	19.7	—	
			3V	—	20.3	—	
	C _L = 15pF	1.2V	0.9V	—	—	43.87	
			1.2V	—	—	12.9	
			1.65V	—	—	10.3	
			2.3V	—	—	9.54	
			3V	—	—	9.34	
	C _L = 15pF	1.65V	0.9V	—	—	40.78	
			1.2V	—	—	9.59	
			1.65V	—	—	6.95	
			2.3V	—	—	5.87	
			3V	—	—	5.07	
	C _L = 15pF	2.3V	0.9V	—	—	41.79	
			1.2V	—	—	8.55	
			1.65V	—	—	5.8	
			2.3V	—	—	4.68	
			3V	—	—	4.27	
C _L = 15pF	3V	0.9V	—	—	43.09		
		1.2V	—	—	8.16		
		1.65V	—	—	4.84		
		2.3V	—	—	4.09		
		3.0V	—	—	3.65		
t_{pLH}/t_{pHL} Propagation delay time low-to-high output / high- to-low output	C _L = 30pF	0.9V	0.9V	—	32.1	—	ns
			1.2V	—	21.3	—	
			1.65V	—	18.7	—	
			2.3V	—	18	—	
			3V	—	18.3	—	
	C _L = 30pF	1.2V	0.9V	—	—	45.65	
			1.2V	—	—	14.76	
			1.65V	—	—	12.37	
			2.3V	—	—	11.61	
			3V	—	—	11.41	
	C _L = 30pF	1.65V	0.9V	—	—	41.72	
			1.2V	—	—	10.65	
			1.65V	—	—	8.01	
			2.3V	—	—	6.94	
			3V	—	—	5.99	
	C _L = 30pF	2.3V	0.9V	—	—	42.44	
			1.2V	—	—	9.26	
			1.65V	—	—	6.51	
			2.3V	—	—	6.39	
			3V	—	—	5.97	
C _L = 30pF	3V	0.9V	—	—	43.69		
		1.2V	—	—	8.8		
		1.65V	—	—	6.48		
		2.3V	—	—	5.72		
		3.0V	—	—	5.28		

Parameter Measurement Information

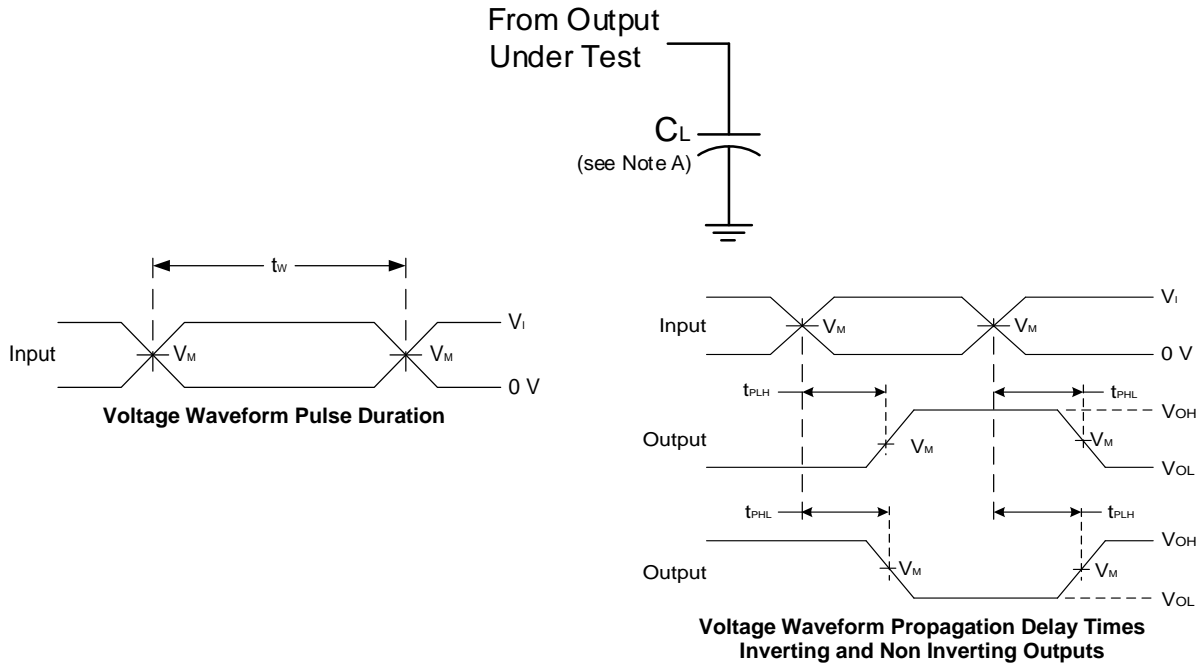
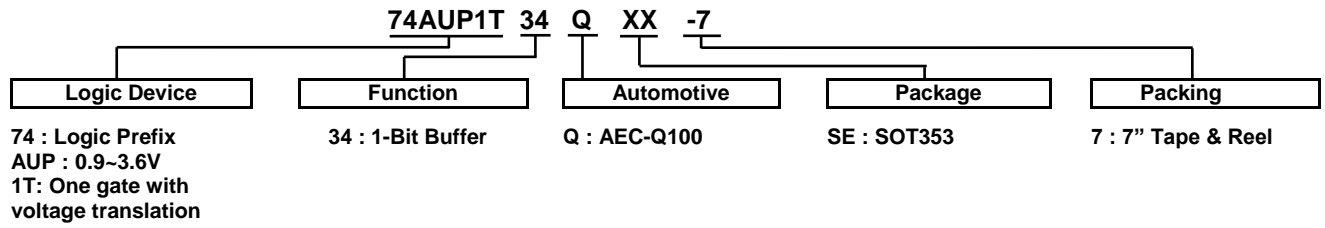


Figure 1. Load Circuit and Voltage Waveforms

- Notes:
- A. Includes test lead and test apparatus capacitance.
 - B. All pulses are supplied at pulse repetition rate $\leq 10\text{MHz}$.
 - C. t_{PLH} and t_{PHL} are the same as t_{PD} .

Ordering Information (Note 8)



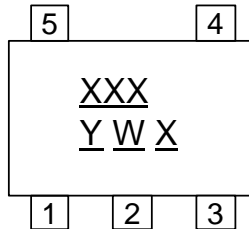
Part Number	Package Code	Package	Packing		
			Quantity	Carrier	Part Number Suffix
74AUP1T34QSE-7	SE	SOT353	3,000	7" Tape and Reel	-7

Note: 8. For packaging details, go to our website at <https://www.diodes.com/design/support/packaging/diodes-packaging/>.

Marking Information

(1) SOT353

(Top View)



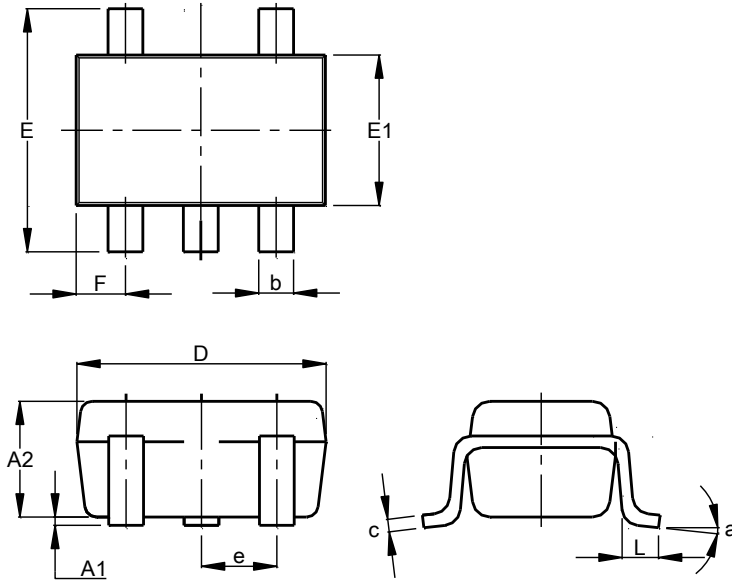
XXX : Identification Code
Y : Year 0 to 9
W : Week : A to Z : 1 to 26 week;
a to z : 27 to 52 week; z represents 52 and 53 week
X : Internal Code

Part Number	Package	Identification Code
74AUP1T34QSE-7	SOT353	4SQ

Package Outline Dimensions

Please see <http://www.diodes.com/package-outlines.html> for the latest version.

SOT353

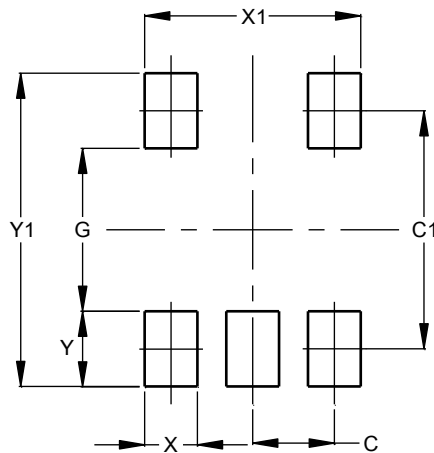


SOT353			
Dim	Min	Max	Typ
A1	0.00	0.10	0.05
A2	0.90	1.00	0.95
b	0.10	0.30	0.25
c	0.10	0.22	0.11
D	1.80	2.20	2.15
E	2.00	2.20	2.10
E1	1.15	1.35	1.30
e	0.650 BSC		
F	0.40	0.45	0.425
L	0.25	0.40	0.30
a	0°	8°	--
All Dimensions in mm			

Suggested Pad Layout

Please see <http://www.diodes.com/package-outlines.html> for the latest version.

SOT353



Dimensions	Value (in mm)
C	0.650
C1	1.900
G	1.300
X	0.420
X1	1.720
Y	0.600
Y1	2.500

Mechanical Data

SOT353

- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish - Mate Tin Plated Leads, Solderable per MIL-STD-202, Method 208 ③
- Weight: 0.006 grams (Approximate)

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